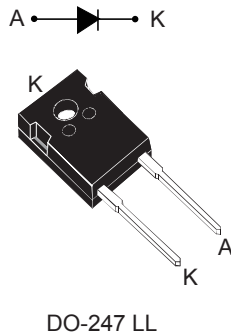



Automotive 1200 V, 40 A power Schottky high surge silicon carbide diode



Features

- AEC-Q101 qualified and PPAP capable 
- None or negligible reverse recovery
- Switching behavior independent of temperature
- Robust high voltage periphery
- Operating T_j from $-55\text{ }^\circ\text{C}$ to $175\text{ }^\circ\text{C}$
- Avalanche energy rated
- ECOPACK2 compliant component

Applications

- Boost PFC
- HEV/EV OBC (On board battery chargers)
- EV Charging station



Description

The SiC diode, available in DO-247 with long leads, is an ultrahigh performance power Schottky rectifier. It is manufactured using a silicon carbide substrate. The wide band-gap material allows the design of a low V_F Schottky diode structure with a 1200 V rating. Thanks to the Schottky construction, no recovery is shown during turn-off and ringing patterns are negligible. The minimal capacitive turn-off behavior is independent of temperature.

Based on latest technology optimization, this diode has an improved forward surge current capability, making it ideal for use in PFC, where this **ST SiC diode** boosts the performance in hard switching conditions while bringing robustness to the design. Its high forward surge capability ensures a good robustness during transient phases.

Product label



Product status link

[STPSC40G12-Y](#)

Product summary

| | |
|--------------|--------|
| $I_{F(AV)}$ | 40 A |
| V_{RRM} | 1200 V |
| T_j (max.) | 175 °C |
| V_F (typ.) | 1.35 V |

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

| Symbol | Parameter | | Value | Unit | |
|----------------|---|---|-----------------------|------|---|
| V_{RRM} | Repetitive peak reverse voltage ($T_j = -40\text{ °C}$ to $+175\text{ °C}$) | | 1200 | V | |
| $E_{AS}^{(1)}$ | Single pulse avalanche energy, starting $T_j = 25\text{ °C}$, $I_{AS} = 9.3\text{ A}$, $L = 10\text{ mH}$ | | 432 | mJ | |
| $I_{F(RMS)}$ | Forward rms current | | 79 | A | |
| $I_{F(AV)}$ | Average forward current | $T_c = 140\text{ °C}$, $\delta = 1$ | 40 | A | |
| I_{FRM} | Repetitive peak forward current | $T_c = 140\text{ °C}$, $T_j = 175\text{ °C}$, $\delta = 0.1$, $f_{sw} > 10\text{ kHz}$ | 158 | A | |
| I_{FSM} | Surge non repetitive forward current | $t_p = 10\text{ ms}$ sinusoidal | $T_c = 25\text{ °C}$ | 280 | A |
| | | | $T_c = 150\text{ °C}$ | 250 | |
| | | $t_p = 10\text{ }\mu\text{s}$ square | $T_c = 25\text{ °C}$ | 1700 | |
| T_{stg} | Storage temperature range | | -65 to +175 | °C | |
| T_j | Operating junction temperature range | | -55 to +175 | °C | |

1. Please refer to [Figure 1](#).

Table 2. Thermal resistance parameters

| Symbol | Parameter | Value | | Unit |
|---------------|------------------|-------|------|------|
| | | Typ. | Max. | |
| $R_{th(j-c)}$ | Junction to case | 0.25 | 0.40 | °C/W |

For more information, please refer to the following application note:

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

| Symbol | Parameter | Test conditions | | Min. | Typ. | Max. | Unit |
|-------------|-------------------------|-----------------------|---------------------|------|------|------|---------------|
| $I_R^{(1)}$ | Reverse leakage current | $T_j = 25\text{ °C}$ | $V_R = V_{RRM}$ | - | 20 | 300 | μA |
| | | $T_j = 150\text{ °C}$ | | - | 67 | 1000 | |
| | | $T_j = 175\text{ °C}$ | | - | 150 | | |
| $V_F^{(2)}$ | Forward voltage drop | $T_j = 25\text{ °C}$ | $I_F = 40\text{ A}$ | - | 1.35 | 1.50 | V |
| | | $T_j = 150\text{ °C}$ | | - | 1.75 | 2.10 | |
| | | $T_j = 175\text{ °C}$ | | - | 1.90 | | |

1. Pulse test: $t_p = 10\text{ ms}$, $\delta < 2\%$

2. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.924 \times I_{F(AV)} + 0.029 \times I_F^2_{(RMS)}$$

For more information, please refer to the following application notes related to the power losses:

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

Table 4. Dynamic electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|----------------|-------------------------|--|------|------|------|------|
| $Q_{Cj}^{(1)}$ | Total capacitive charge | $V_R = 800\text{ V}$ | - | 202 | - | nC |
| C_j | Total capacitance | $V_R = 0\text{ V}, T_c = 25\text{ }^\circ\text{C}, F = 1\text{ MHz}$ | - | 3078 | - | pF |
| | | $V_R = 800\text{ V}, T_c = 25\text{ }^\circ\text{C}, F = 1\text{ MHz}$ | - | 141 | - | |

1. Most accurate value for the capacitive charge: $Q_{Cj}(V_R) = \int_0^{V_R} C_j(V) dV$

Figure 1. Current and voltage waveforms for avalanche energy test across D.U.T (device under test)

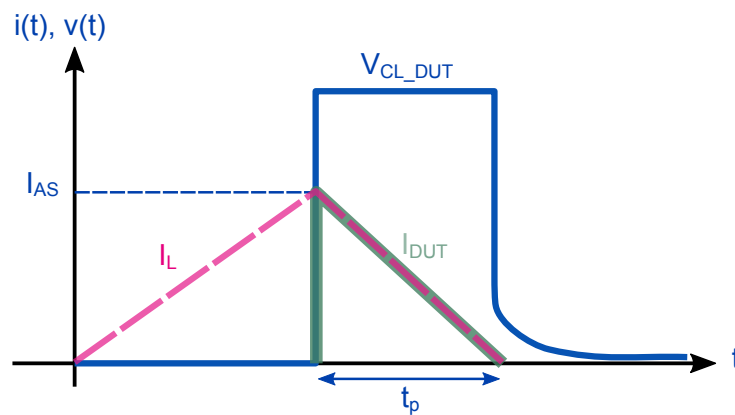


Figure 2. Thermal transient impedance model circuit of the diode – $Z_{th(j-c)}$

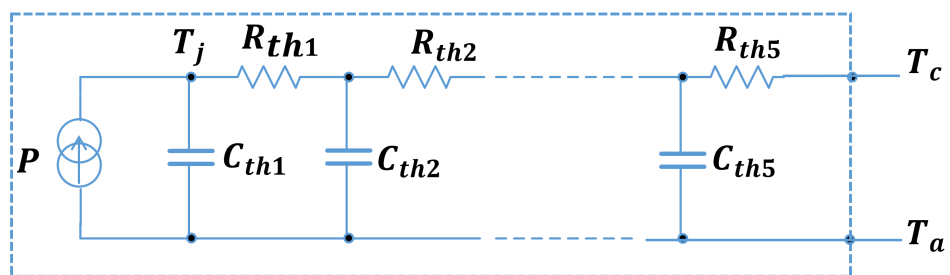


Table 5. Components typical values of the diode thermal transient impedance model $Z_{th(j-c)}$

| Ref. | Value (K/W) | Ref. | Value (J/K) |
|-----------|-------------|-----------|-------------|
| R_{th1} | 11.3m | C_{th1} | 3.52m |
| R_{th2} | 63.6m | C_{th2} | 4.04m |
| R_{th3} | 89.7m | C_{th3} | 18.5m |
| R_{th4} | 66m | C_{th4} | 87.2m |
| R_{th5} | 19.4m | C_{th5} | 1.13 |

1.1 Characteristics (curves)

Figure 3. Forward voltage drop versus forward current (typical values)

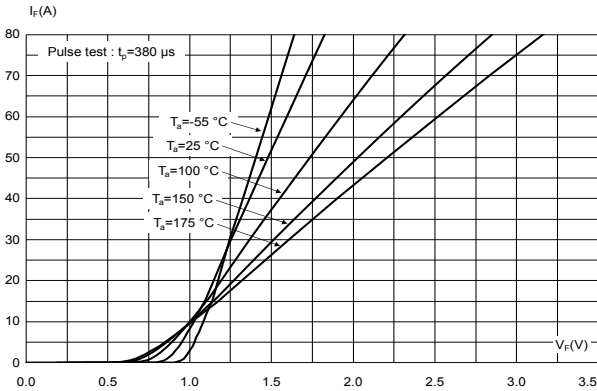


Figure 4. Reverse leakage current versus reverse voltage applied (typical values)

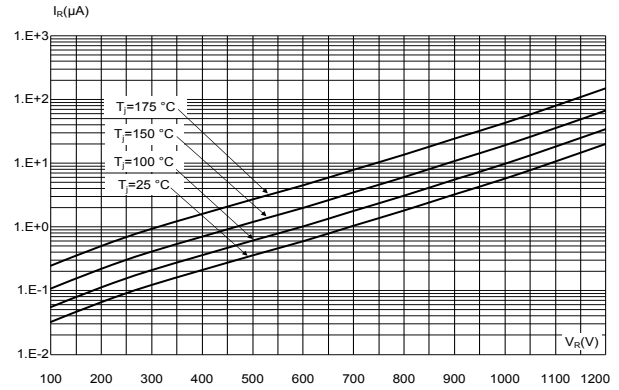


Figure 5. Peak forward current versus case temperature

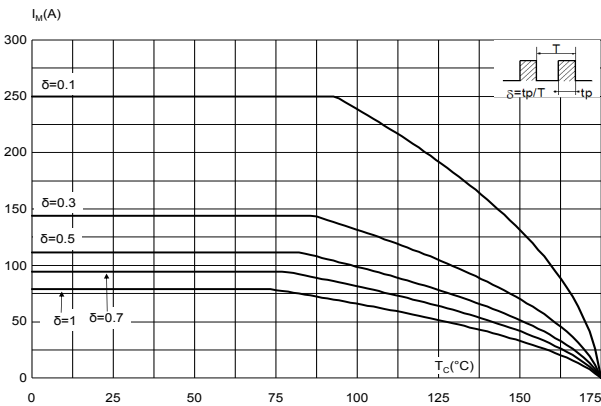


Figure 6. Junction capacitance versus reverse voltage applied (typical values)

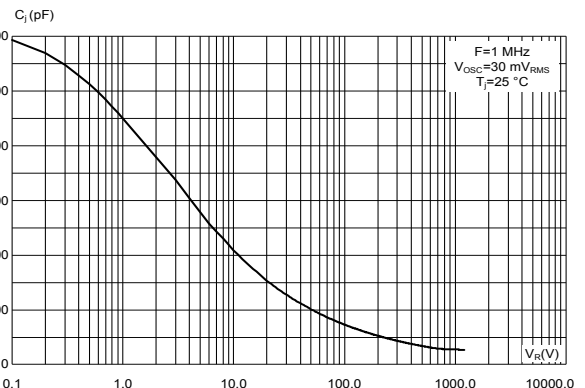


Figure 7. Relative variation of thermal impedance junction to case versus pulse duration

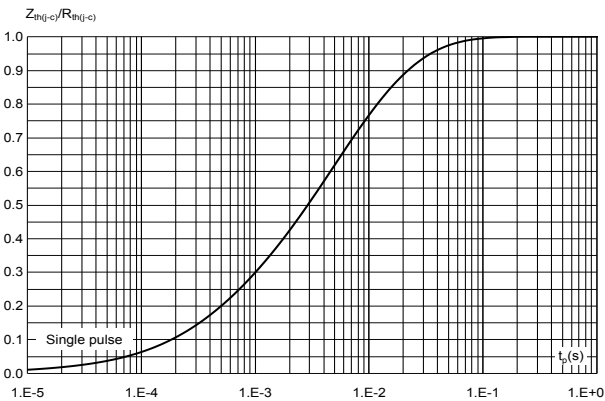


Figure 8. Non-repetitive peak surge forward current versus pulse duration (sinusoidal waveform)

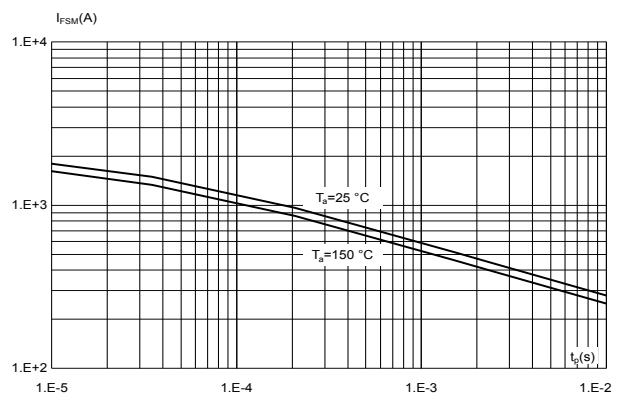
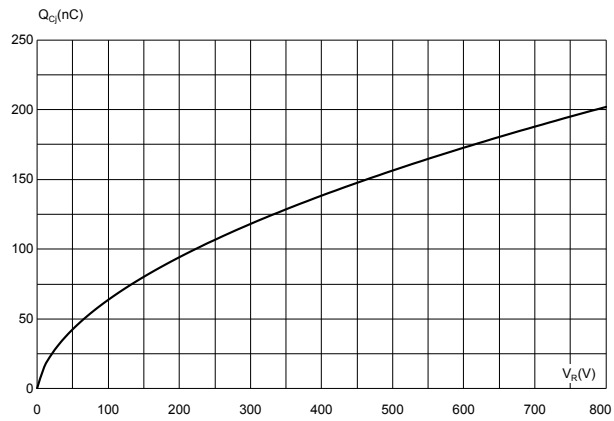


Figure 9. Total capacitive charges versus reverse voltage applied (typical values)



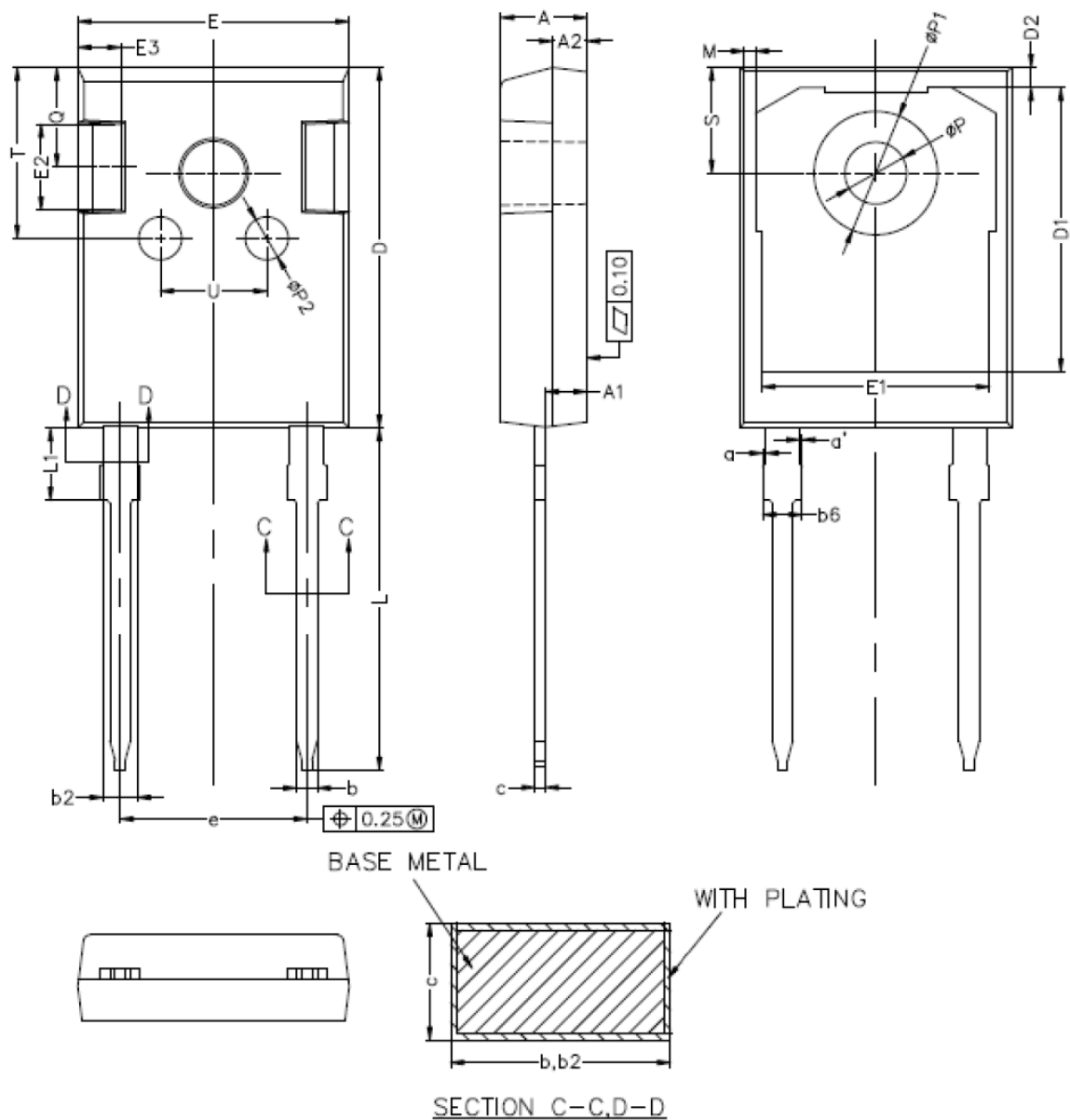
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 DO-247 LL package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N·m
- Maximum torque value: 1.0 N·m

Figure 10. DO-247 LL package outline



Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 6. DO-247 LL package mechanical data

| Ref. | Dimensions | | | | | |
|------|-------------|-------|-------|-----------------------------|-------|-------|
| | Millimeters | | | Inches (for reference only) | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.90 | 5.00 | 5.10 | 0.192 | 0.197 | 0.201 |
| A1 | 2.31 | 2.41 | 2.51 | 0.090 | 0.095 | 0.099 |
| A2 | 1.90 | 2.00 | 2.10 | 0.074 | 0.079 | 0.083 |
| a | 0.00 | | 0.15 | 0.000 | | 0.006 |
| a' | 0.00 | | 0.15 | 0.000 | | 0.006 |
| b | 1.16 | | 1.29 | 0.045 | | 0.051 |
| b2 | 1.96 | | 2.06 | 0.077 | | 0.082 |
| b6 | | | 2.25 | | | 0.089 |
| c | 0.59 | | 0.66 | 0.023 | | 0.026 |
| D | 20.90 | 21.00 | 21.10 | 0.822 | 0.827 | 0.831 |
| D1 | 16.25 | 16.55 | 16.85 | 0.639 | 0.652 | 0.664 |
| D2 | 1.05 | 1.20 | 1.35 | 0.041 | 0.047 | 0.054 |
| E | 15.70 | 15.80 | 15.90 | 0.618 | 0.622 | 0.626 |
| E1 | 13.06 | 13.26 | 13.46 | 0.514 | 0.522 | 0.530 |
| E2 | 4.90 | 5.00 | 5.10 | 0.192 | 0.197 | 0.201 |
| E3 | 2.40 | 2.50 | 2.60 | 0.094 | 0.098 | 0.103 |
| e | 10.78 | 10.88 | 10.98 | 0.424 | 0.428 | 0.433 |
| L | 19.80 | 19.92 | 20.10 | 0.779 | 0.784 | 0.792 |
| L1 | 3.93 | | 4.46 | 0.154 | | 0.176 |
| M | 0.35 | | 0.95 | 0.013 | | 0.038 |
| P | 3.50 | 3.60 | 3.70 | 0.137 | 0.142 | 0.146 |
| P1 | 7.00 | | 7.40 | 0.275 | | 0.292 |
| P2 | 2.40 | 2.50 | 2.60 | 0.094 | 0.098 | 0.103 |
| Q | 5.60 | | 6.00 | 0.220 | | 0.237 |
| S | 6.05 | 6.15 | 6.25 | 0.238 | 0.242 | 0.247 |
| T | 9.80 | | 10.20 | 0.385 | | 0.402 |
| U | 6.00 | | 6.40 | 0.236 | | 0.252 |

3 Ordering information

Table 7. Ordering information

| Order code | Marking | Package | Weight | Base qty. | Delivery mode |
|---------------|---------------|----------|--------|-----------|---------------|
| STPSC40G12WLY | STPSC40G12WLY | DO-247LL | 5.9 g | 30 | Tube |

Revision history

Table 8. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 09-Nov-2022 | 1 | Initial release. |

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